

HIGH SPEED, HIGH VOLTAGE SWITCHING APPLICATIONS.

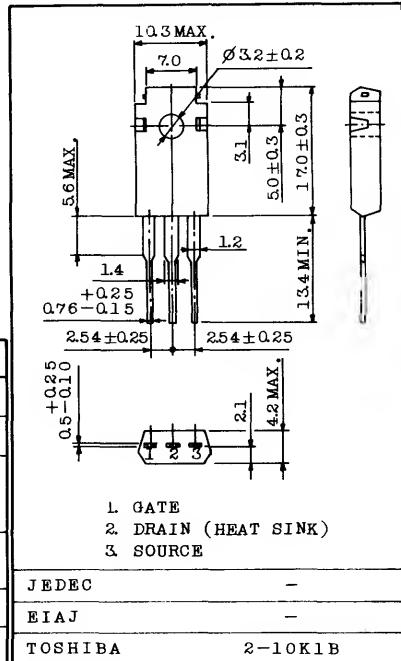
SWITCHING REGULATOR, DC-DC CONVERTER AND MOTOR DRIVE APPLICATIONS.

## FEATURES:

- High Breakdown Voltage :  $V(BR)DSS=400V$
- High Forward Transfer Admittance :  $|Y_{fs}|=1.2S$  (Typ.)
- Low Leakage Current :  $I_{GSS}=\pm 100nA$ (Max.) @  $V_{GS}=\pm 20V$   
 $I_{DSS}=1mA$ (Max.) @  $V_{DS}=400V$
- Enhancement-Mode :  $V_{th}=1.5 \sim 3.5V$  @  $I_D=1mA$

MAXIMUM RATINGS ( $T_a=25^\circ C$ )

CHARACTERISTIC		SYMBOL	RATING	UNIT
Drain-Source Voltage		$V_{DSX}$	400	V
Gate-Source Voltage		$V_{GSS}$	$\pm 20$	V
Drain Current	DC	$I_D$	2	A
	Pulse	$I_{DP}$	4	
Drain Power Dissipation ( $T_c=25^\circ C$ )		$P_D$	50	W
Channel Temperature		$T_{ch}$	150	$^\circ C$
Storage Temperature Range		$T_{stg}$	-55 ~ 150	$^\circ C$

INDUSTRIAL APPLICATIONS  
Unit in mm

Weight : 2.0g

ELECTRICAL CHARACTERISTICS ( $T_a=25^\circ C$ )

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT	
Gate Leakage Current	$I_{GSS}$	$V_{GS}=\pm 20V, V_{DS}=0$	-	-	$\pm 100$	nA	
Drain Cut-off Current	$I_{DSS}$	$V_{DS}=400V, V_{GS}=0$	-	-	1.0	mA	
Drain-Source Breakdown Voltage	$V(BR)DSS$	$I_D=10mA, V_{GS}=0$	400	-	-	V	
Gate Threshold Voltage	$V_{th}$	$V_{DS}=10V, I_D=1mA$	1.5	-	3.5	V	
Forward Transfer Admittance	$ Y_{fs} $	$V_{DS}=10V, I_D=1A$	0.6	1.2	-	S	
Drain-Source ON Resistance	$R_{DS(ON)}$	$I_D=1A, V_{GS}=10V$	-	1.6	2.2	$\Omega$	
Drain-Source ON Voltage	$V_{DS(ON)}$	$I_D=4A, V_{GS}=10V$	-	8.5	12	V	
Input Capacitance	$C_{iss}$	$V_{DS}=10V, V_{GS}=0, f=1MHz$	-	410	600	pF	
Reverse Transfer Capacitance	$C_{rss}$	$V_{DS}=10V, V_{GS}=0, f=1MHz$	-	35	70	pF	
Output Capacitance	$C_{oss}$	$V_{DS}=10V, V_{GS}=0, f=1MHz$	-	115	170	pF	
Switching Time	Rise Time	$t_r$	$I_D=1A$ 	-	15	30	ns
	Turn-on Time	$t_{on}$		-	30	60	ns
	Fall Time	$t_f$		-	30	60	ns
	Turn-off Time	$t_{off}$		-	100	200	ns

THIS TRANSISTOR IS THE ELECTROSTATIC SENSITIVE DEVICE. PLEASE HANDLE WITH CAUTION.